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## FDS6630A

### N-Channel Logic Level PowerTrench™ MOSFET

#### General Description

This N-Channel Logic Level MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain superior switching performance.

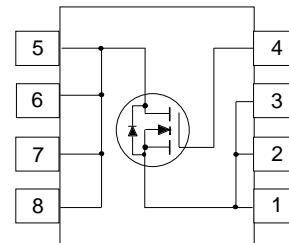
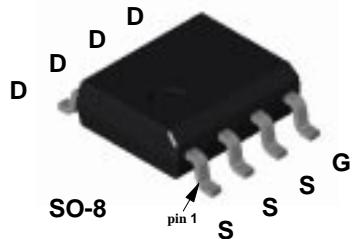
These devices are well suited for low voltage and battery powered applications where low in-line power loss and fast switching are required.

#### Applications

- DC/DC converter
- Load switch
- Motor drives

#### Features

- 6.5 A, 30 V.  $R_{DS(on)} = 0.038 \Omega$  @  $V_{GS} = 10$  V  
 $R_{DS(on)} = 0.053 \Omega$  @  $V_{GS} = 4.5$  V
- Low gate charge (5nC typical).
- Fast switching speed.
- High performance trench technology for extremely low  $R_{DS(ON)}$ .
- High power and current handling capability.



#### Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DSS}$	Drain-Source Voltage	30	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current - Continuous (Note 1a)	6.5	A
	- Pulsed	40	
$P_D$	Power Dissipation for Single Operation (Note 1a)	2.5	W
	(Note 1b)	1.2	
	(Note 1c)	1	
$T_J, T_{stg}$	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

#### Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1a)	50	$^\circ\text{C/W}$
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case (Note 1)	25	$^\circ\text{C/W}$

#### Package Outlines and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
FDS6630A	FDS6630A	13"	12mm	2500 units

**Electrical Characteristics** $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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**Off Characteristics**

$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}$ , $I_D = 250 \mu\text{A}$	30			V
$\Delta BV_{DSS}$ $\Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$ , Referenced to $25^\circ\text{C}$		24		$\text{mV}/^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}$ , $V_{GS} = 0 \text{ V}$			1	$\mu\text{A}$
$I_{GSSF}$	Gate-Body Leakage Current, Forward	$V_{GS} = 20 \text{ V}$ , $V_{DS} = 0 \text{ V}$			100	nA
$I_{GSSR}$	Gate-Body Leakage Current, Reverse	$V_{GS} = -20 \text{ V}$ , $V_{DS} = 0 \text{ V}$			-100	nA

**On Characteristics** (Note 2)

$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250 \mu\text{A}$	1	1.7	3	V
$\Delta V_{GS(\text{th})}$ $\Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}$ , Referenced to $25^\circ\text{C}$		-4		$\text{mV}/^\circ\text{C}$
$R_{DS(\text{on})}$	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}$ , $I_D = 6.5 \text{ A}$ $V_{GS} = 10 \text{ V}$ , $I_D = 6.5 \text{ A}$ , $T_J = 125^\circ\text{C}$ $V_{GS} = 4.5 \text{ V}$ , $I_D = 5.5 \text{ A}$		0.028 0.044 0.040	0.038 0.060 0.053	$\Omega$
$I_{D(\text{on})}$	On-State Drain Current	$V_{GS} = 10 \text{ V}$ , $V_{DS} = 5 \text{ V}$	20			A
$g_{FS}$	Forward Transconductance	$V_{DS} = 5 \text{ V}$ , $I_D = 6.5 \text{ A}$		13		S

**Dynamic Characteristics**

$C_{iss}$	Input Capacitance	$V_{DS} = 15 \text{ V}$ , $V_{GS} = 0 \text{ V}$ , $f = 1.0 \text{ MHz}$		460		pF
$C_{oss}$	Output Capacitance			115		pF
$C_{rss}$	Reverse Transfer Capacitance			45		pF

**Switching Characteristics** (Note 2)

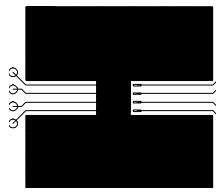
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 15 \text{ V}$ , $I_D = 1 \text{ A}$ , $V_{GS} = 10 \text{ V}$ , $R_{\text{GEN}} = 6 \Omega$		5	11	ns
$t_r$	Turn-On Rise Time			8	17	ns
$t_{d(off)}$	Turn-Off Delay Time			17	28	ns
$t_f$	Turn-Off Fall Time			13	24	ns
$Q_g$	Total Gate Charge	$V_{DS} = 5 \text{ V}$ , $I_D = 6.5 \text{ A}$ , $V_{GS} = 5 \text{ V}$		5	7	nC
$Q_{gs}$	Gate-Source Charge			2		nC
$Q_{gd}$	Gate-Drain Charge			0.9		nC

**Drain-Source Diode Characteristics and Maximum Ratings**

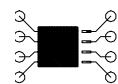
$I_S$	Maximum Continuous Drain-Source Diode Forward Current			2.1	A	
$V_{SD}$	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}$ , $I_S = 2.1 \text{ A}$ (Note 2)		0.8	1.2	V

## Notes:

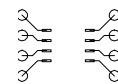
1:  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a) 50° C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz. copper.



b) 105° C/W when mounted on a 0.04 in<sup>2</sup> pad of 2 oz. copper.



c) 125° C/W on a 0.006 in<sup>2</sup> pad of 2 oz. copper.

Scale 1 : 1 on letter size paper

2: Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

## Typical Characteristics

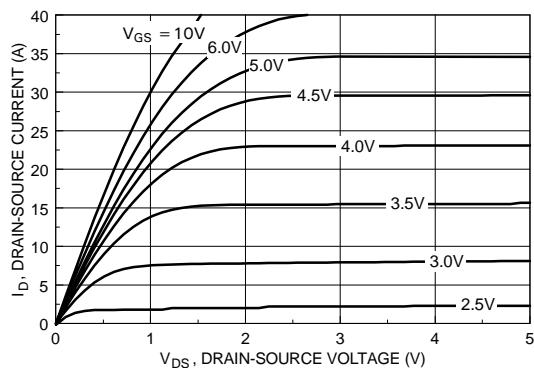


Figure 1. On-Region Characteristics.

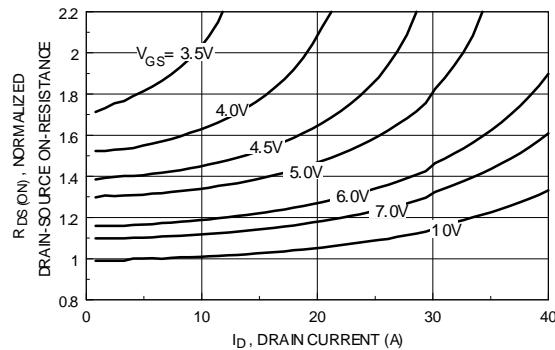


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

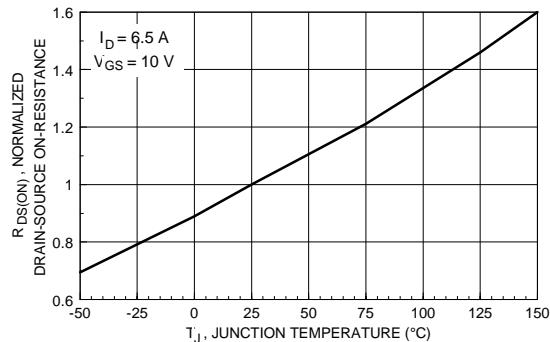


Figure 3. On-Resistance Variation with Temperature.

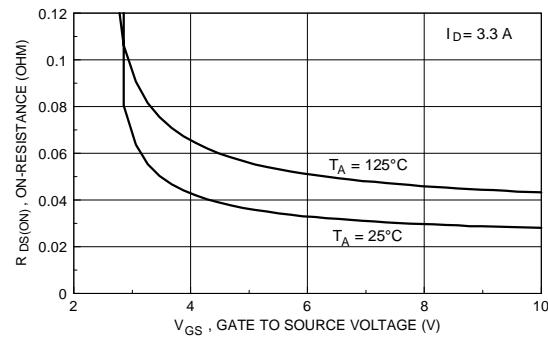


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

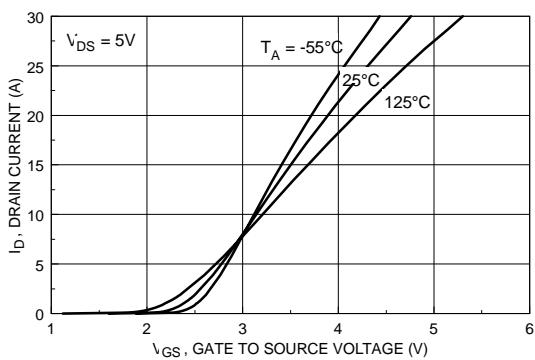


Figure 5. Transfer Characteristics.

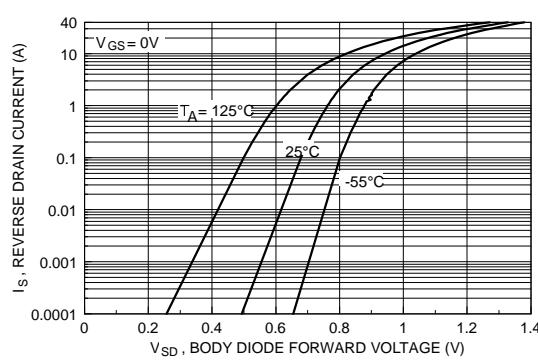


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

## Typical Characteristics (continued)

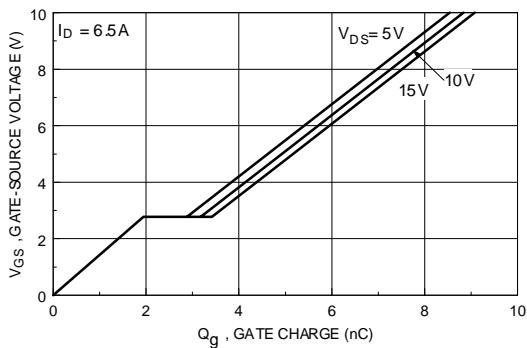


Figure 7. Gate-Charge Characteristics.

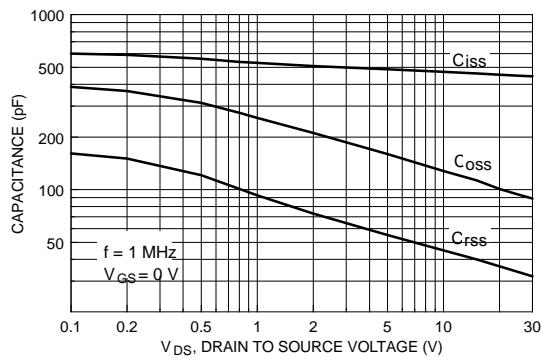


Figure 8. Capacitance Characteristics.

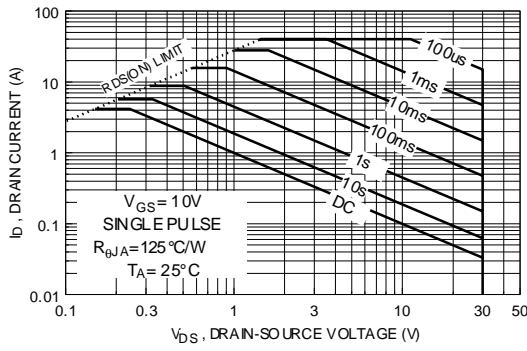


Figure 9. Maximum Safe Operating Area.

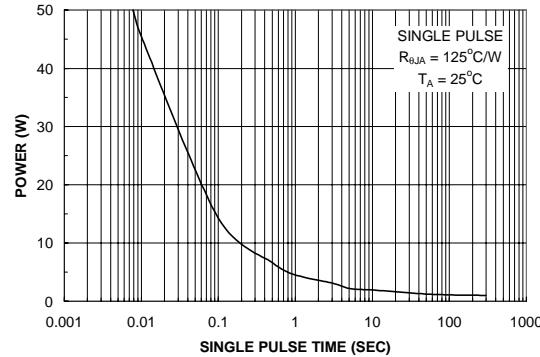


Figure 10. Single Pulse Maximum Power Dissipation.

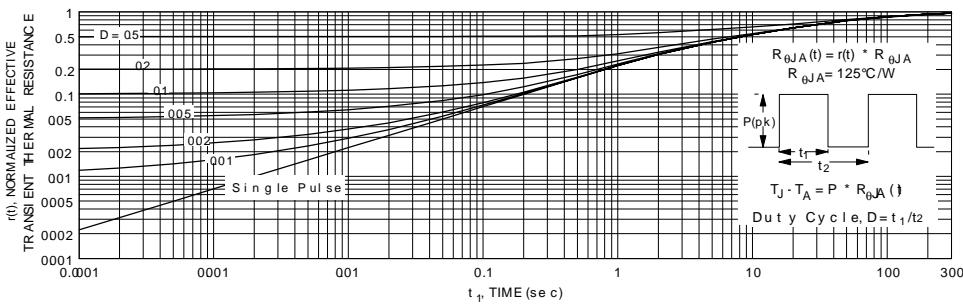


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1c.  
Transient thermal response will change depending on the circuit board design.

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